



GaN-based UV photodiode

Model: GS-ABC-2835S

General Features:

- UVA+UVB+UVC photodiode
- Photovoltaic mode operation
- SMD 2835 package
- Good visible blindness
- High responsivity and low dark current

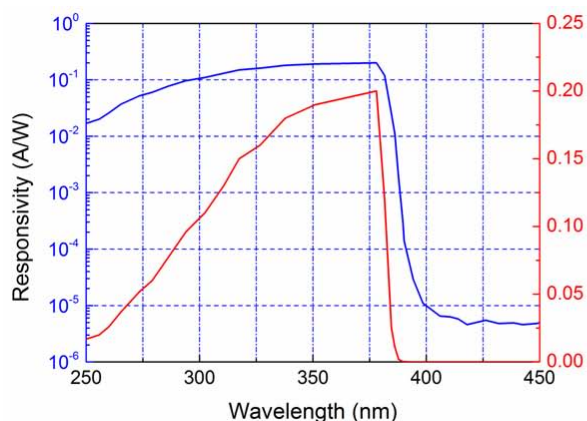


Applications: UV index monitoring, UV radiation dose measurement, flame detection

Specifications:

Parameters	Symbol	Value	Unit
Maximum ratings			
Operation temperature range	T_{opt}	-25-85	$^{\circ}C$
Storage temperature range	T_{sto}	-40-85	$^{\circ}C$
Soldering temperature (3 s)	T_{sol}	260	$^{\circ}C$
Reverse voltage	V_{r-max}	-10	V
General characteristics (25 $^{\circ}C$)			
Chip size	A	0.11	mm^2
Dark current ($V_r = -1$ V)	I_d	<1	nA
Temperature coefficient	T_c	-0.02	%/ $^{\circ}C$
Capacitance (at 0 V and 1 MHz)	C_p	3.8	pF
Spectral response characteristics (25 $^{\circ}C$)			
Wavelength of peak responsivity	λ_p	355	nm
Peak responsivity (at 355 nm)	R_{max}	0.20	A/W
Spectral response range ($R=0.1 \times R_{max}$)	-	210-370	nm
UV-visible rejection ratio ($R_{max}/R_{400\text{ nm}}$)	-	$>10^4$	-

Spectral response



Package dimensions

